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Theoretical developments and applications in excited-state calculations James R. Chelikowsky, Jack R. Deslippe, Felipe H. da Jornada, Steven G. Louie, Jeffrey B. Neaton, Johannes Lischner, Fang Liu, Diana Y. Qiu, Jaime S. de Sousa, Sahar Sharifzadeh, Derek Vigil-Fowler, Chao Yang

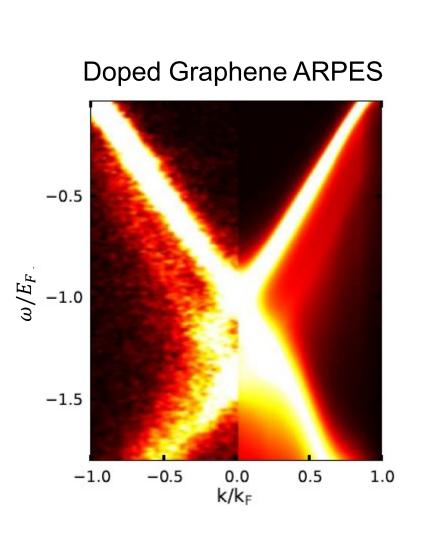
Nature of Plasmon Satellites in P

Motivation

- · Plasmons and their interactions with electrons and holes are of increasing interest for technological applications, such as plasmonics and catalysis.
- Goal: Understand the nature of plasmon satellites that appear in the angle-resolved photoemission spectroscopy (ARPES) measurements on doped graphene and bulk Si.

Doped Graphene

- Previous GW calculations based on simplified models of electron systems, such as the linear-bands model for graphene and the electron gas, predicted the existence of a composite particle, the plasmaron, consisting of a hole and a plasmon.
- ARPES experiments on doped graphene showing significant plasmon satellites appeared to support this theory.
- Ab initio treatment of substrate and the GW plus cumulant expansion (GW+C) of the interacting green's function give ARPES spectra in good agreement with experiment for all momenta measured.
- No plasmaron appears in spectra, only weak plasmon satellites.
- Agreement of previous theoretical work with experiment was due to cancellation of errors in use of GW approximation and overestimation the screening from the substrate.



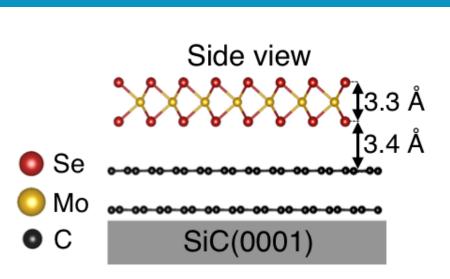
Effect of Substrate Screening on the Quasip

Motivation

- Transition metal dichalcogenides, such as MoS2 and MoSe2, are interesting candidate materials for electronic and photovoltaic applications.
- Goal: Understand the role of substrate used in experiments on the quasiparticle and excitonic properties of MoSe2.

In-Plane Substrate Approximation

• Experimental collaboration: both scanning tunneling spectroscopy and photoluminescense measurements were performed on the same sample.



- Challenge: calculate quasiparticle band structure and exciton binding energy of monolayer MoSe₂ including the screening from the substrate. The MoSe2 monolayer is only commensurable with the substrate on a 3x3 supercell
- We developed an *ab initio* method to calculate the screening from the substrate without having to construct a large supercell for the material + substrate.
- Idea: we fully consider the perpendicular component of the screening, but neglect in-plane local fields:

$$\tilde{\chi}_{\mathbf{G}\mathbf{G}'}^{0,\mathrm{bilayer}}(\mathbf{q}) = \chi_{\mathbf{G}\mathbf{G}'}^{0,\mathrm{bilayer}}(\mathbf{q}) \,\delta_{\mathbf{G}_x\mathbf{G}'_x}\delta_{\mathbf{G}_y\mathbf{G}'_y}$$

$$\Delta \varepsilon_{\mathbf{G}\mathbf{G}'}^{-1}(\mathbf{q})$$

 $= \left[1 - v(\chi^{0,\text{MoSe2}}(\mathbf{q}) + \tilde{\chi}^{0,\text{bilayer}}(\mathbf{q}))\right]_{cc'}^{-1}$

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| hotoemission Spectroscopy | | | |
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| | Bulk S |) | |
| First measurement calculation of ARPES of bulk Si, including satellite peaks. GW+C again give agreement with ea and gives no plasmare | S spectra QP and es good xperiment | $ \begin{array}{c} 0 \\ -5 \\ -6 \\ -5 \\ -10 \\ -5 \\ -10 \\ -5 \\ -10 \\ -5 \\ -1.0 \\ -0.5 \\ 0.0 \\ 0.5 \\ 1.0 \\ 1.5 \\ 2.0 \\ k_{\parallel} [2 \pi/a] \\ $ | 2.5 -1.0 -0.5 0.0 0.5 1.0 1.5 2.0 2 $k_{\parallel} [2 \pi/a]$ |
| | Conclusi | ons | |
| While sufficient for ca insufficient for satellite | • • | | |
| The plasmaron is an exist in nature. Common model dielee | | | |
| | Future W | orks | |
| Understand electron- applications. | -plasmon coup | ling on surfac | es for catalytic |
| Include extrinsic con agreement of QP and | | • | • |
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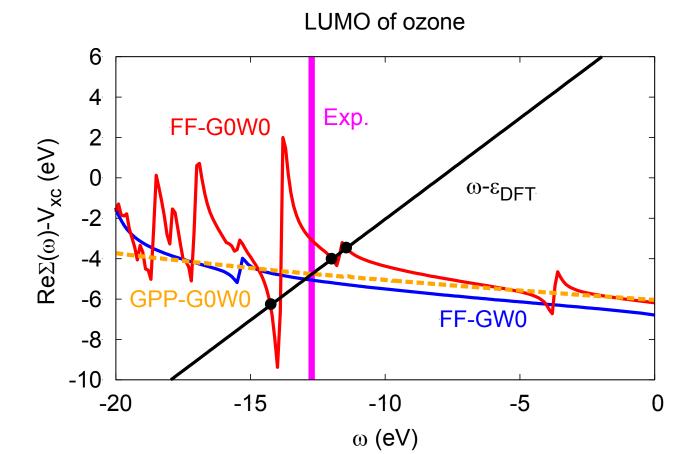
Accurate GW calculations for closed-shell molecules.

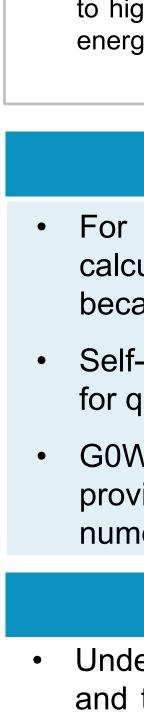
Motivation

- Knowledge of quasiparticle energies of molecules is important for interpreting spectroscopy experiments and the design of novel devices for energy technology, such as Graetzel cells or OLEDs.
- Goal: Understanding the effects of self-consistency, full-frequency approaches and generalized plasmon-pole models on quasiparticle energies in closed-shell molecules.

Pitfalls in full-frequency G0W0 calculations

- In molecules, the frequency-dependent electron self energy exhibits poles which describe shake-up excitations consisting of a guasiparticle and an electron-hole pair.
- For molecules with a small HOMO-LUMO gap, the self-energy poles can occur at unphysically low energies inducing large errors in the computed quasiparticle energies.
- Replacing the DFT Kohn-Sham energies by quasiparticle energies within a self-consistent GW0 approach pushes the self-energy poles to higher energies and results in good agreement with experiment.





Efficiency and Accuracy of PW-PP GW Calculations

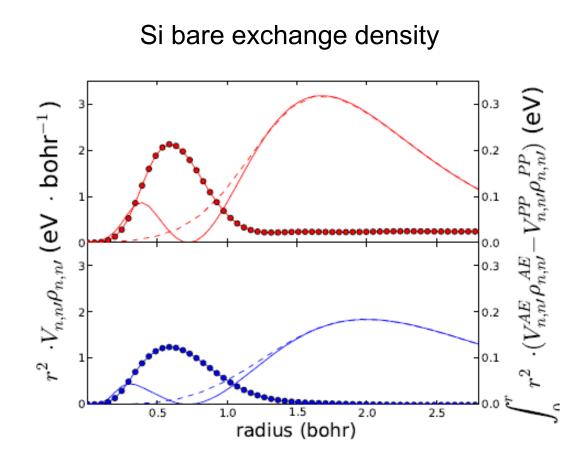
Motivation

Efficient methods for calculating the QP properties of large systems are needed to adequately treat systems of current interest, including materials with defects and complex materials with large unit cells.

Goal: To understand the effect of the plane-wave pseudopotential (PW-PP) approximation on the accuracy of GW calculations.

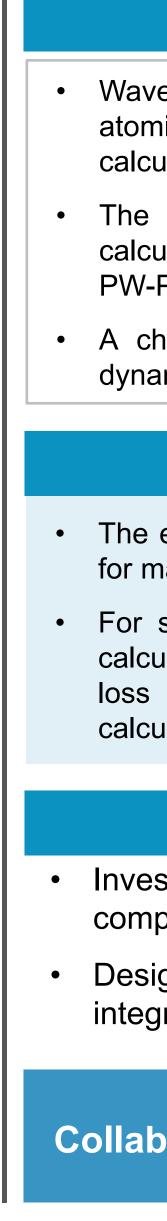
Contributions to bare exchange coming from states that have a small (large) separation between outer and inner wavefunction peaks are smaller (larger) for PW-GW calculations PP AE GW relative to calculation.

Atomic



Atomic Si, Ga, As, and Ar show small differences in bare exchange between all-electron (AE) and PW-PP GW calculations (~1%).

Trends are robust across all atoms studied, which vary in localization of electrons and presence of d-states, indicating the trends are robust across different system types.

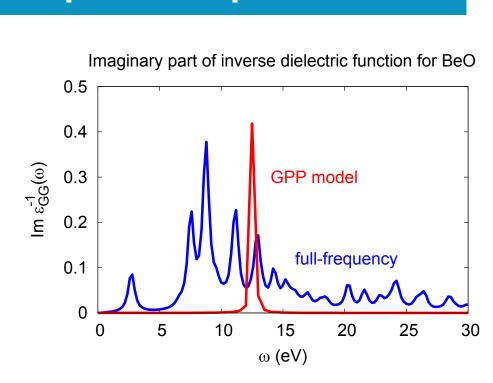


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G0W0 calculations with a generalized plasmon-pole model

The generalized plasmon-pole model replaces the complicated dielectric response of a molecule by a single excitations which must have a high energy to fulfill the f-sum

As a result, the self-energy poles are shifted to higher energies and accurate quasiparticle energies are obtained.



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Conclusions

• For molecules with small HOMO-LUMO gaps, full-frequency G0W0 calculations can result in large errors for quasiparticle energies because of unphysical self-energy poles.

Self-consistent GW0 calculations give good agreement with experiment for quasiparticle energies.

GOW0 calculations employing a generalized plasmon pole model provide accurate quasiparticle energies at a significantly lower numerical cost than self-consistent full-frequency GW0 calculations.

Future Works

• Understand the effects of full-frequency approaches, self-consistency and the generalized plasmon-pole model on quasiparticle energies in other systems, such as oxide materials.

Johannes Lischner, Sahar Sharifzadeh, Jack R. Deslippe, Theory: Collaborators Jeffrey R. Neaton and Steven G. Louie

Bulk

• Wavefunctions in the bulk have larger inner-outer peak separation than in the atomic case due to bonding. The bare exchange is larger for PW-PP GW calculations, as expected from the atomic case.

• The valence band has a larger difference between PW-PP and AE GW calculations than the conduction band, leading to an opening of the gap for PW-PP GW calculations, on the order of 0.1-0.2 eV.

A cheap correction scheme is to perform a PW-PP calculation for the dynamical self energy and get bare exchange from AE calculation.

Conclusions

• The error due to the PW-PP approximation is small, on the order 0.1-0.2 eV for many standard semiconductors.

For systems with deep cores, this error can be reduced to ~0.05 eV by calculating only the bare exchange in the AE formalism, with only a minimal loss in computational efficiency. This could be very useful for accurate calculations on large systems.

Future Works

• Investigate efficacy of PAW formalism for shallow-core systems, where computational efficiency is drastically reduced with PW-PP GW.

Design improved pseudopotentials including accurate exchange integrals as constraint during generation.

Collaborators

Theory:

Derek Vigil-Fowler, Brad D. Malone and Steven G. Louie

MSD Materials Sciences Division